



BIPOLAR ANALOG INTEGRATED CIRCUIT

μ PC3236TK

5 V, SILICON GERMANIUM MMIC MEDIUM OUTPUT POWER AMPLIFIER

DESCRIPTION

The μ PC3236TK is a silicon germanium carbon (SiGe:C) monolithic integrated circuit designed as IF amplifier for DBS LNB.

This device exhibits low noise figure and high power gain characteristics.

This IC is manufactured using our UHS4 (Ultra High Speed Process) SiGe:C bipolar process.

FEATURES

- Low current : $I_{CC} = 24.0$ mA TYP.
- Medium output power : $P_{O(sat)} = +15.5$ dBm TYP. @ $f = 1.0$ GHz
: $P_{O(sat)} = +10.5$ dBm TYP. @ $f = 2.2$ GHz
- High linearity : $P_{O(1dB)} = +11$ dBm TYP. @ $f = 1.0$ GHz
: $P_{O(1dB)} = +7.5$ dBm TYP. @ $f = 2.2$ GHz
- Power gain : $G_P = 38$ dB TYP. @ $f = 1.0$ GHz
: $G_P = 38$ dB TYP. @ $f = 2.2$ GHz
- Gain flatness : $\Delta G_P = 1.0$ dB TYP. @ $f = 1.0$ to 2.2 GHz
- Noise Figure : $NF = 2.6$ dB TYP. @ $f = 1.0$ GHz
: $NF = 2.6$ dB TYP. @ $f = 2.2$ GHz
- Supply voltage : $V_{CC} = 4.5$ to 5.5 V
- Port impedance : input/output 50Ω

APPLICATIONS

- IF amplifiers in DBS LNB, other L-band amplifiers, etc.

ORDERING INFORMATION

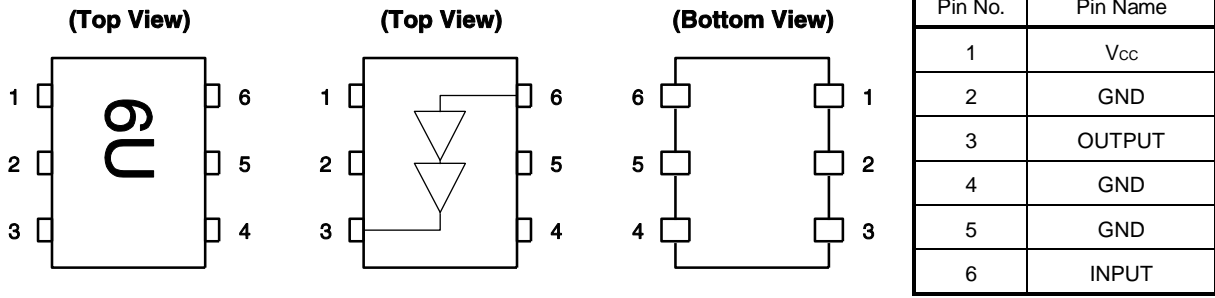
Part Number	Order Number	Package	Marking	Supplying Form
μ PC3236TK-E2	μ PC3236TK-E2-A	6-pin lead-less minimold (1511 PKG) (Pb-Free)	6U	<ul style="list-style-type: none">• Embossed tape 8 mm wide• Pin 1, 6 face the perforation side of the tape• Qty 5 kpcs/reel

Remark To order evaluation samples, please contact your nearby sales office
Part number for sample order: μ PC3236TK-A

Caution: Observe precautions when handling because these devices are sensitive to electrostatic discharge

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



PRODUCT LINE-UP OF 5 V-BIAS SILICON MMIC MEDIUM OUTPUT POWER AMPLIFIER
 (T_A = +25°C, f = 1 GHz, V_{CC} = V_{out} = 5.0 V, Z_s = Z_L = 50 Ω)

Part No.	I _{CC} (mA)	G _P (dB)	NF (dB)	P _O (1dB) (dBm)	P _O (sat) (dBm)	Package	Marking
μ PC2708TB	26	15.0	6.5	–	+10.0	6-pin super minimold	C1D
μ PC2709TB	25	23.0	5.0	–	+11.5		C1E
μ PC2710TB	22	33.0	3.5	–	+13.5		C1F
μ PC2776TB	25	23.0	6.0	–	+8.5		C2L
μ PC3223TB	19	23.0	4.5	+6.5	+12.0		C3J
μ PC3225TB	24.5	32.5 ^{Note}	3.7 ^{Note}	+9 ^{Note}	+15.5 ^{Note}		C3M
μ PC3226TB	15.5	25.0	5.3	+7.5	+13.0		C3N
μ PC3232TB	26	32.8	4.0	+11	+15.5		C3S
μ PC3236TK	24	38	2.6	+11	+15.5	6-pin lead-less minimold (1511 PKG)	6U

Note μ PC3225TB is f = 0.95 GHz

Remark Typical performance. Please refer to **ELECTRICAL CHARACTERISTICS** in detail.

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Conditions	Ratings	Unit
Supply Voltage	V _{CC}	T _A = +25°C, pin 1 and 3	6.0	V
Power Dissipation	P _D	T _A = +85°C Note	232	mW
Operating Ambient Temperature	T _A		-40 to +85	°C
Storage Temperature	T _{stg}		-55 to +150	°C
Input Power	P _{in}	T _A = +25°C	0	dBm

Note Mounted on double-sided copper-clad 50 × 50 × 1.6 mm epoxy glass PWB

RECOMMENDED OPERATING RANGE

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Supply Voltage	V _{CC}	The same voltage should be applied to pin 1 and 3.	4.5	5.0	5.5	V
Operating Ambient Temperature	T _A		-40	+25	+85	°C

ELECTRICAL CHARACTERISTICS (T_A = +25°C, V_{CC} = V_{out} = 5.0 V, Z_S = Z_L = 50 Ω)

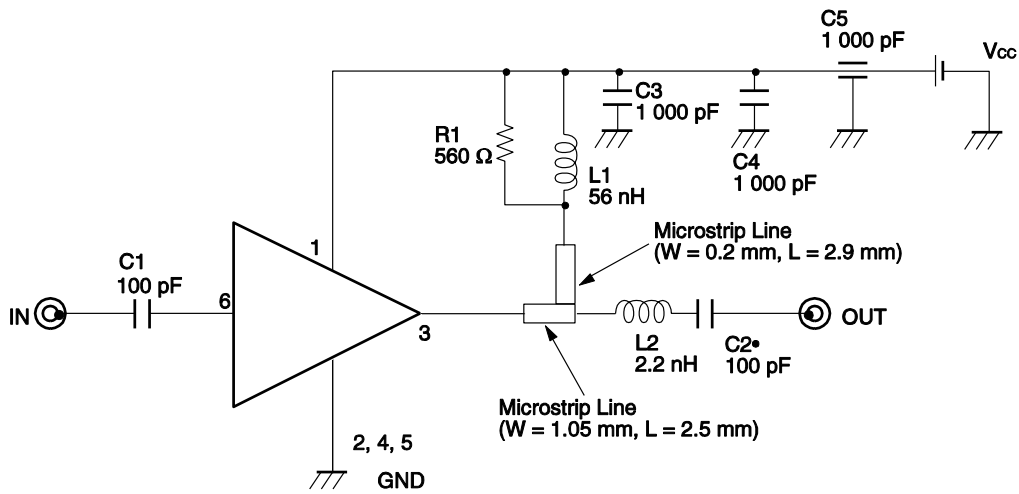
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Circuit Current	I _{CC}	No input signal	19	24	31	mA
Power Gain 1	G _{P1}	f = 0.25 GHz, P _{in} = -40 dBm	34	37	39	dB
Power Gain 2	G _{P2}	f = 1.0 GHz, P _{in} = -40 dBm	35.5	38	40.5	
Power Gain 3	G _{P3}	f = 1.8 GHz, P _{in} = -40 dBm	36	39	42	
Power Gain 4	G _{P4}	f = 2.2 GHz, P _{in} = -40 dBm	35	38	41	
Saturated Output Power 1	P _{O(sat)1}	f = 1.0 GHz, P _{in} = 0 dBm	+13.5	+15.5	-	dBm
Saturated Output Power 2	P _{O(sat)2}	f = 2.2 GHz, P _{in} = -5 dBm	+8.5	+10.5	-	
Gain 1 dB Compression Output Power 1	P _{O(1dB)1}	f = 1.0 GHz	+8	+11	-	dBm
Gain 1 dB Compression Output Power 2	P _{O(1dB)2}	f = 2.2 GHz	+5	+7.5	-	
Noise Figure 1	NF1	f = 1.0 GHz	-	2.6	3.5	dB
Noise Figure 2	NF2	f = 2.2 GHz	-	2.6	3.5	
Isolation 1	ISL1	f = 1.0 GHz, P _{in} = -40 dBm	43	50	-	dB
Isolation 2	ISL2	f = 2.2 GHz, P _{in} = -40 dBm	43	50	-	
Input Return Loss 1	RL _{in1}	f = 1.0 GHz, P _{in} = -40 dBm	6	9	-	dB
Input Return Loss 2	RL _{in2}	f = 2.2 GHz, P _{in} = -40 dBm	6.5	9.5	-	
Output Return Loss 1	RL _{out1}	f = 1.0 GHz, P _{in} = -40 dBm	8	11	-	dB
Output Return Loss 2	RL _{out2}	f = 2.2 GHz, P _{in} = -40 dBm	7	10	-	

STANDARD CHARACTERISTICS FOR REFERENCE

(T_A = +25°C, V_{CC} = V_{out} = 5.0 V, Z_S = Z_L = 50 Ω, unless otherwise specified)

Parameter	Symbol	Test Conditions	Reference Value	Unit
Power Gain 5	G _{P5}	f = 2.6 GHz, P _{in} = -40 dBm	36	dB
Power Gain 6	G _{P6}	f = 3.0 GHz, P _{in} = -40 dBm	32.5	
Gain Flatness	ΔG _P	f = 1.0 to 2.2 GHz, P _{in} = -40 dBm	1.0	dB
K factor 1	K1	f = 1.0 GHz, P _{in} = -40 dBm	1.6	-
K factor 2	K2	f = 2.2 GHz, P _{in} = -40 dBm	1.6	-
Output 3rd Order Intercept Point 1	OIP ₃₁	f1 = 1 000 MHz, f2 = 1 001 MHz	23	dBm
Output 3rd Order Intercept Point 2	OIP ₃₂	f1 = 2 200 MHz, f2 = 2 201 MHz	16.5	
2nd Order Intermodulation Distortion	IM ₂	f1 = 1 000 MHz, f2 = 1 001 MHz, P _{out} = -5 dBm/tone	45	dBc
2nd Harmonic	2f ₀	f ₀ = 1.0 GHz, P _{out} = -15 dBm	58	dBc

TEST CIRCUIT



The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

COMPONENTS OF TEST CIRCUIT FOR MEASURING ELECTRICAL CHARACTERISTICS

	Type	Value
R1	Chip Resistance	560 Ω
L1	Chip Inductor	56 nH
L2	Chip Inductor	2.2 nH
C1, C2	Chip Capacitor	100 pF
C3, C4	Chip Capacitor	1 000 pF
C5	Feed-through Capacitor	1 000 pF

INDUCTOR FOR THE OUTPUT PIN

The internal output transistor of this IC, to output medium power. To supply current for output transistor, connect an inductor between the Vcc pin (pin 1) and output pin (pin 3). Select inductance, as the value listed above.

The inductor has both DC and AC effects. In terms of DC, the inductor biases the output transistor with minimum voltage drop to output enable high level. In terms of AC, the inductor makes output-port impedance higher to get enough gain. In this case, large inductance and Q is suitable (Refer to the following page).

CAPACITORS FOR THE Vcc, INPUT AND OUTPUT PINS

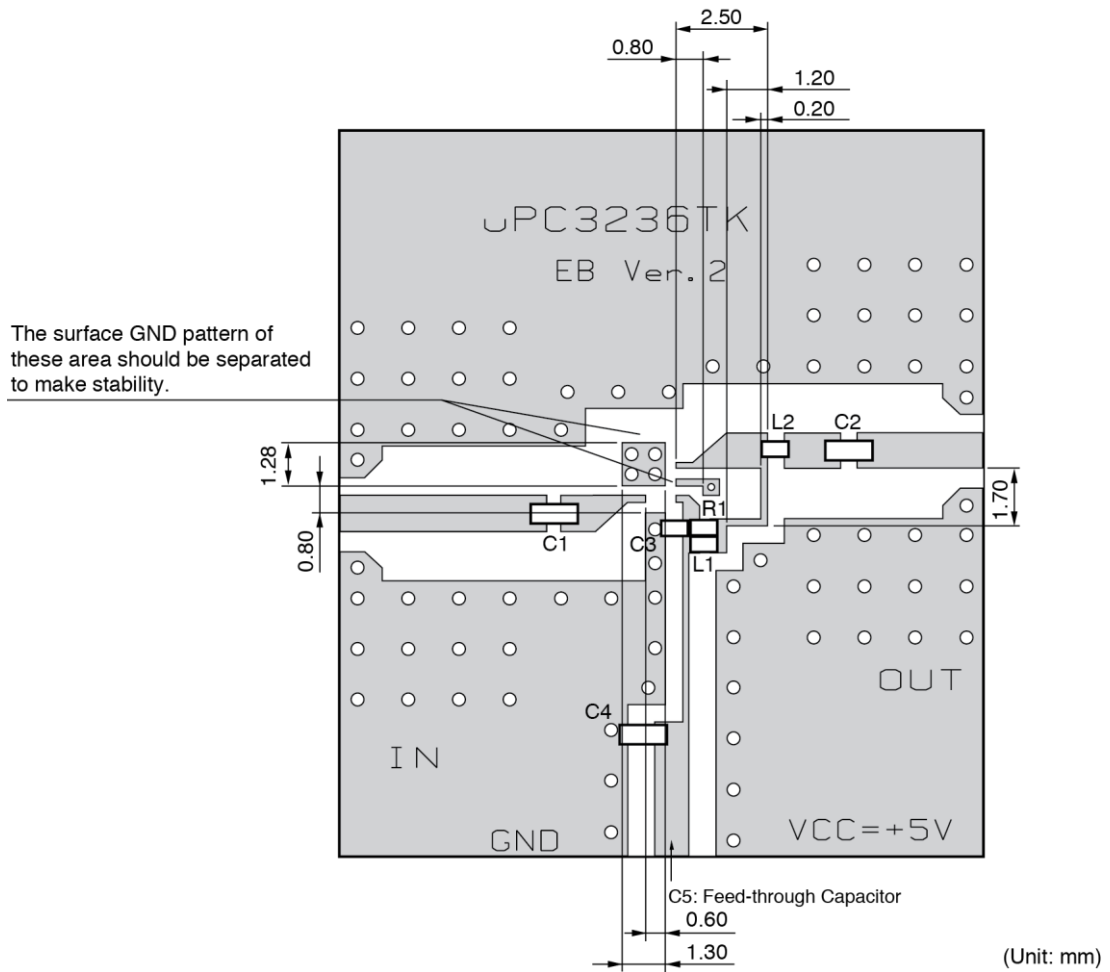
Capacitors of 1 000 pF are recommendable as the bypass capacitor for the Vcc pin and the coupling capacitors for the input and output pins.

The bypass capacitor connected to the Vcc pin is used to minimize ground impedance of Vcc pin. So, stable bias can be supplied against Vcc fluctuation.

The coupling capacitors, connected to the input and output pins, are used to cut the DC and minimize RF serial impedance. Their capacitances are therefore selected as lower impedance against a 50 Ω load. The capacitors thus perform as high pass filters, suppressing low frequencies to DC.

To obtain a flat gain from 100 MHz upwards, 1 000 pF capacitors are used in the test circuit. In the case of under 10 MHz operation, increase the value of coupling capacitor such as 10 000 pF. Because the coupling capacitors are determined by equation, $C = 1/(2 \pi Rfc)$.

ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD



COMPONENT LIST

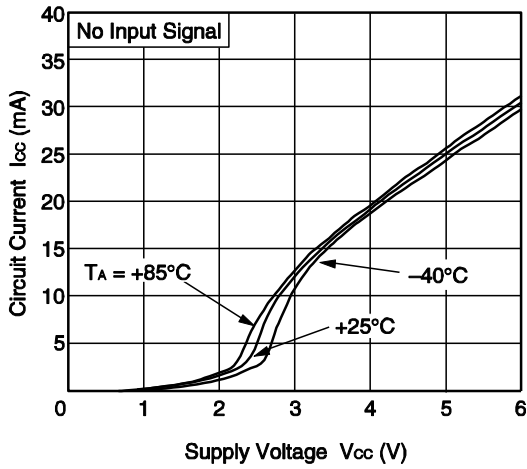
	Value	Size
R1	560 Ω	1005
L1	56 nH	1005
L2	2.2 nH	1005
C1, C2	100 pF	1608
C3	1 000 pF	1005
C4	1 000 pF	1608
C5	1 000 pF	Feed-through Capacitor

Notes

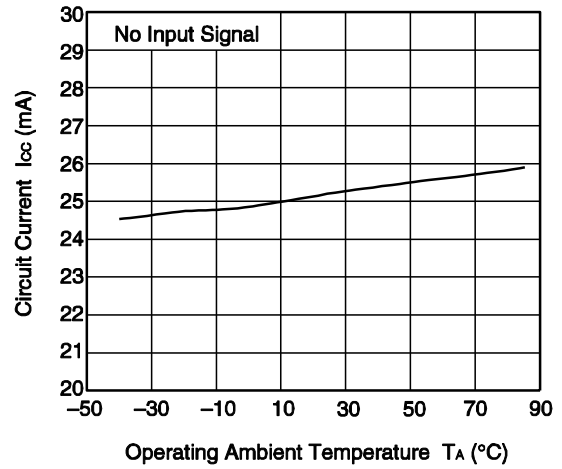
1. 19 × 21.46 × 0.51 mm double sided 18 μm copper clad RO4003C (Rogers) board.
2. Back side: GND pattern
3. Au plated on pattern
4. ○○ : Through holes (φ0.40, φ0.30)
5. L1, L2: FDK's products

TYPICAL CHARACTERISTICS ($T_A = +25^\circ\text{C}$, $V_{CC} = V_{out} = 5.0\text{ V}$, $Z_s = Z_L = 50\ \Omega$, unless otherwise specified)

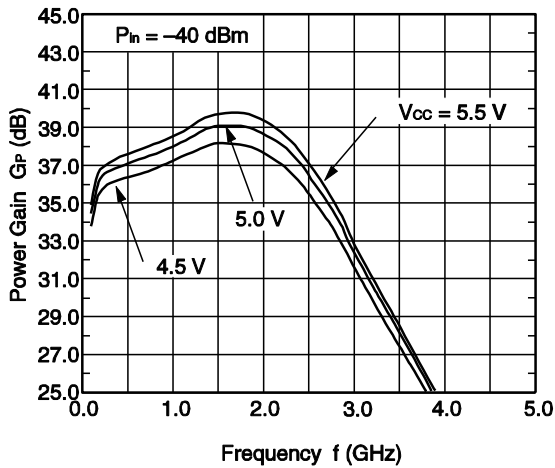
CIRCUIT CURRENT vs. SUPPLY VOLTAGE



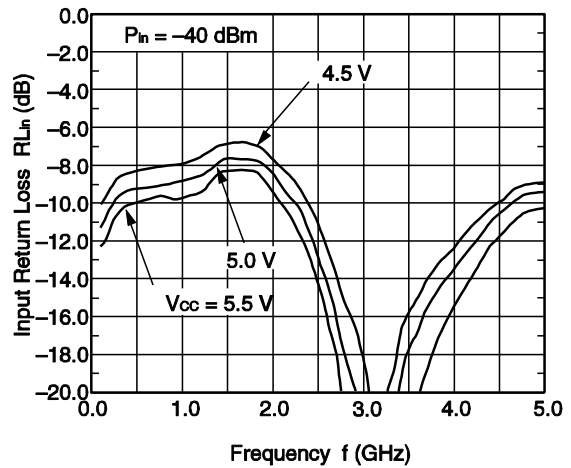
CURCUIT CURRENT vs. OPERATING AMBIENT TEMPERATURE



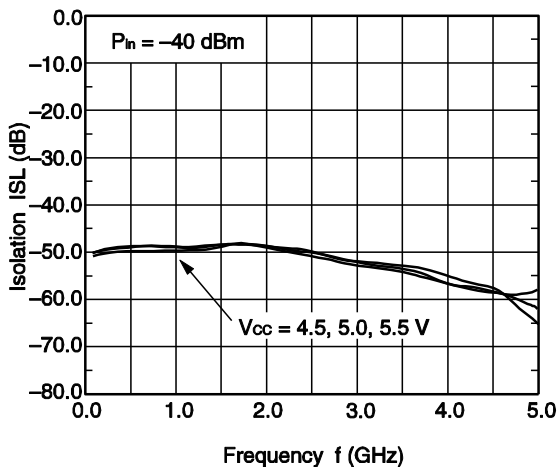
POWER GAIN vs. FREQUENCY



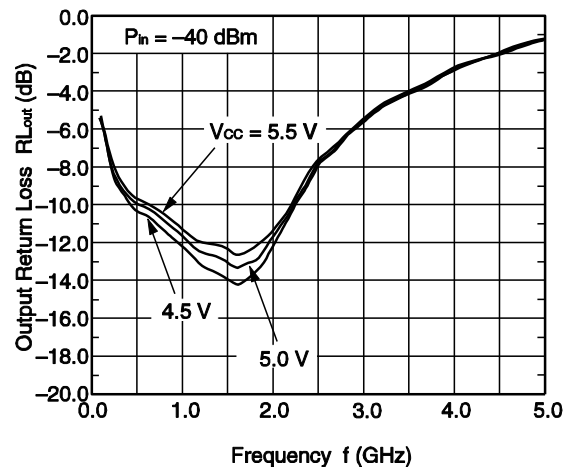
INPUT RETURN LOSS vs. FREQUENCY



ISOLATION vs. FREQUENCY

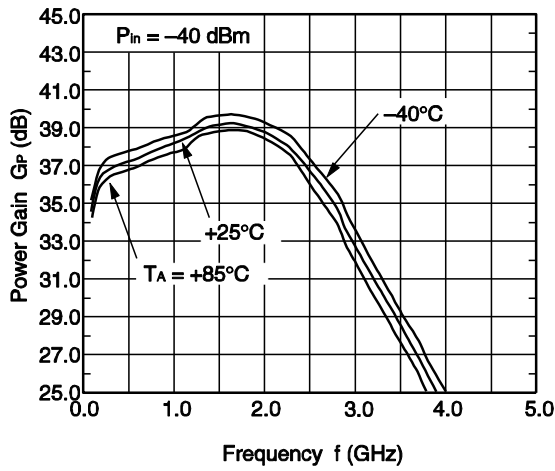


OUTPUT RETURN LOSS vs. FREQUENCY

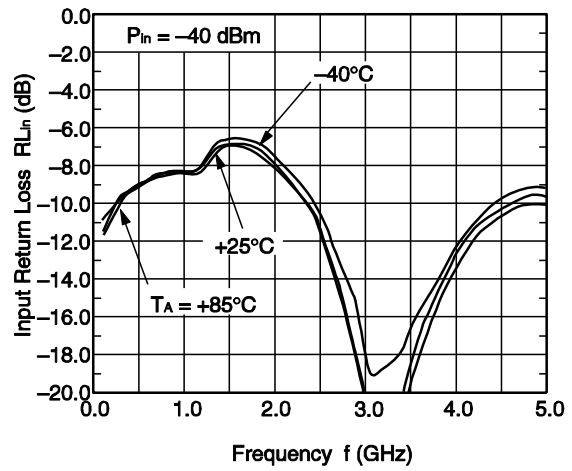


Remark The graphs indicate nominal characteristics.

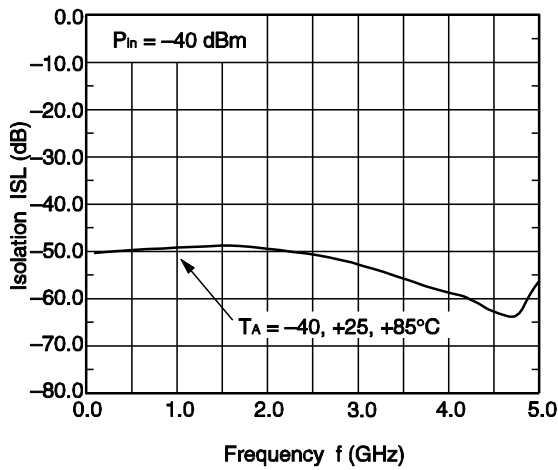
POWER GAIN vs. FREQUENCY



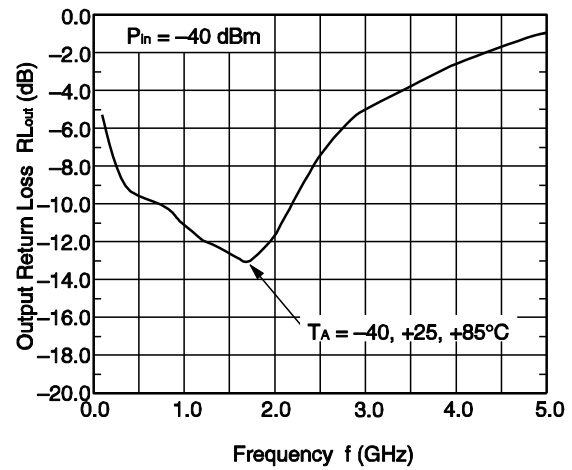
INPUT RETURN LOSS vs. FREQUENCY



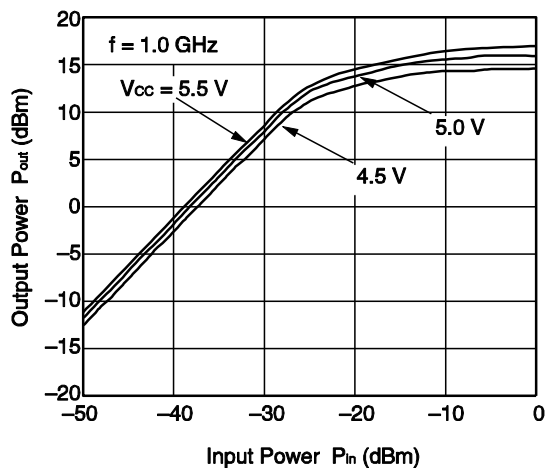
ISOLATION vs. FREQUENCY



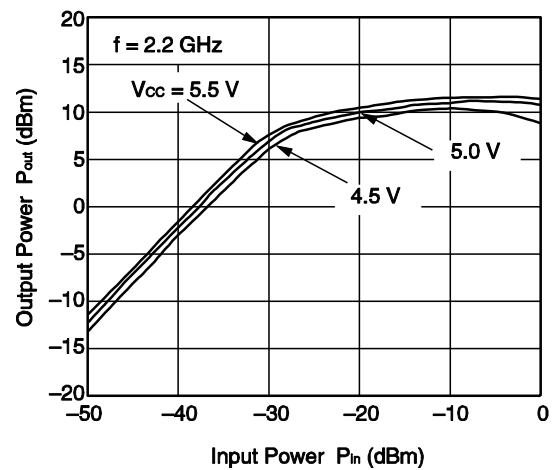
OUTPUT RETURN LOSS vs. FREQUENCY



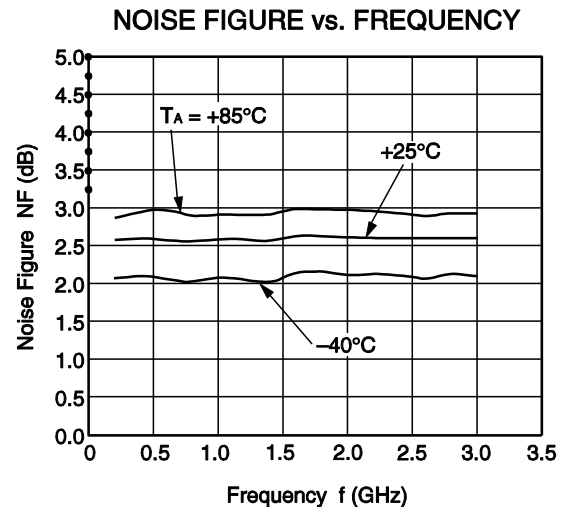
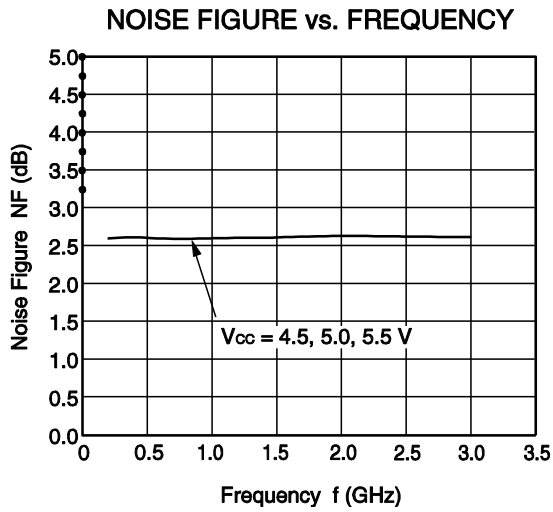
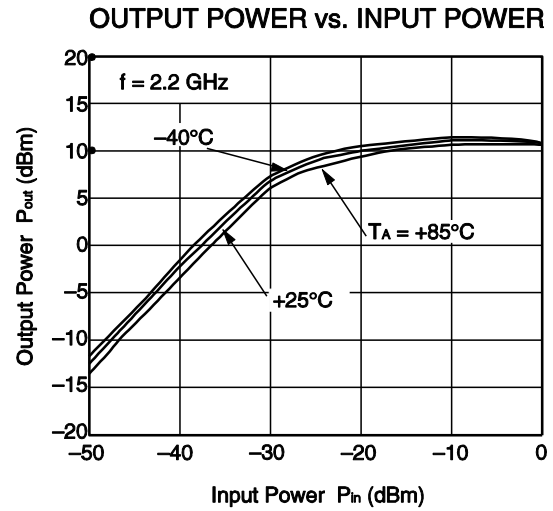
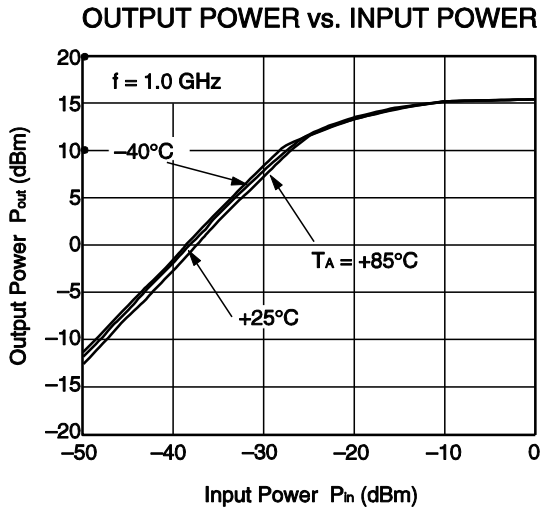
OUTPUT POWER vs. INPUT POWER



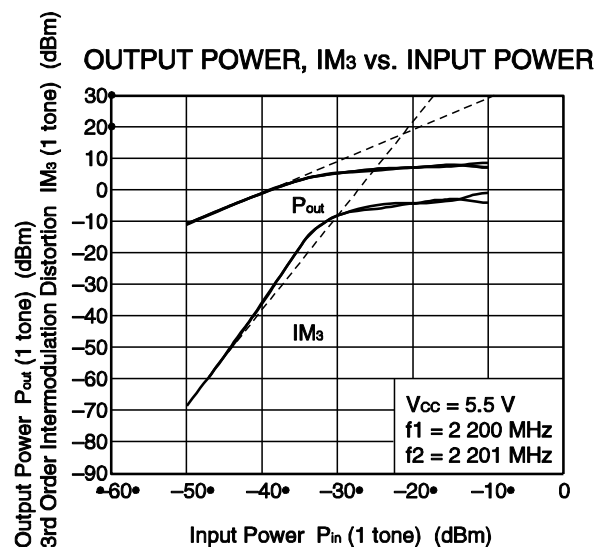
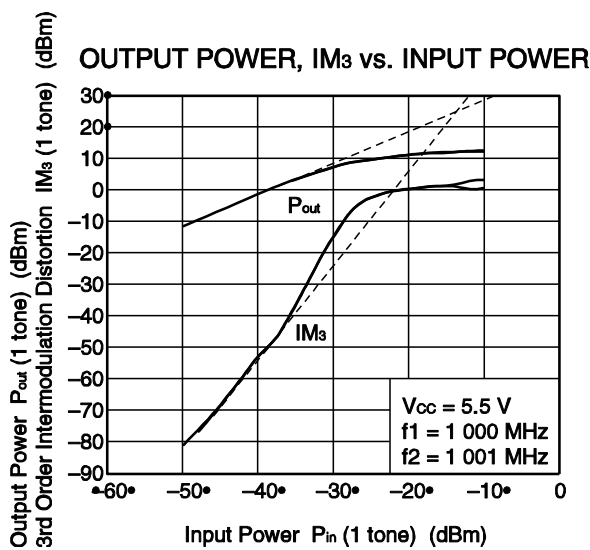
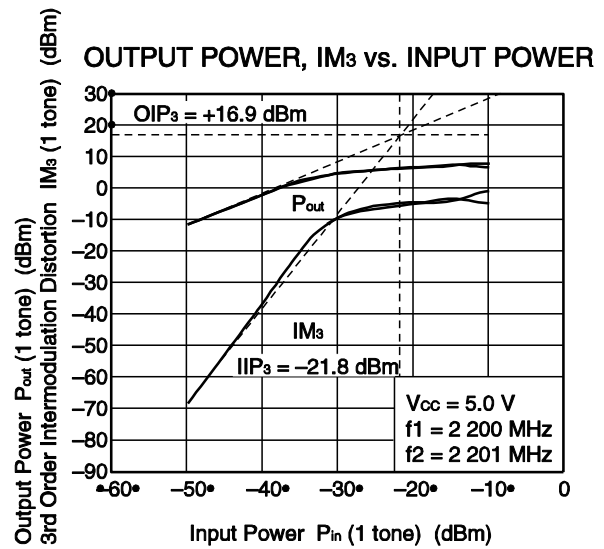
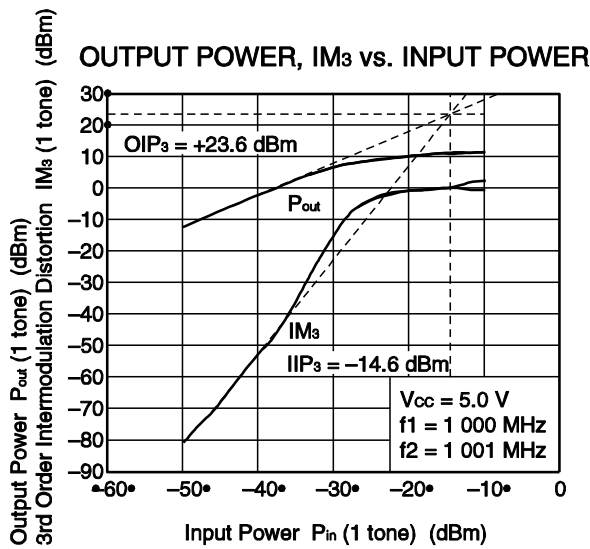
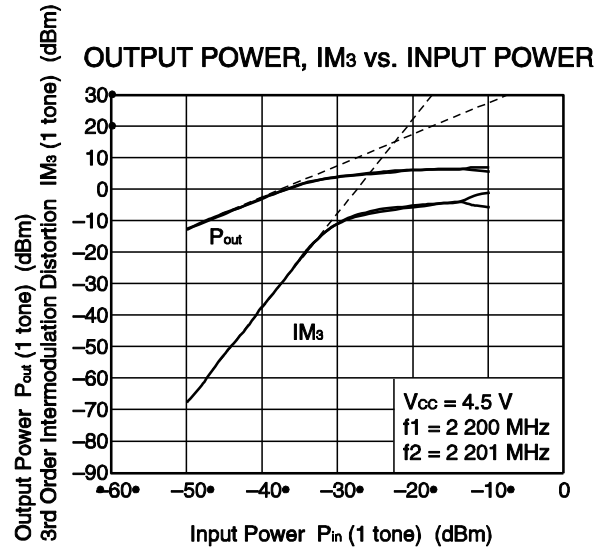
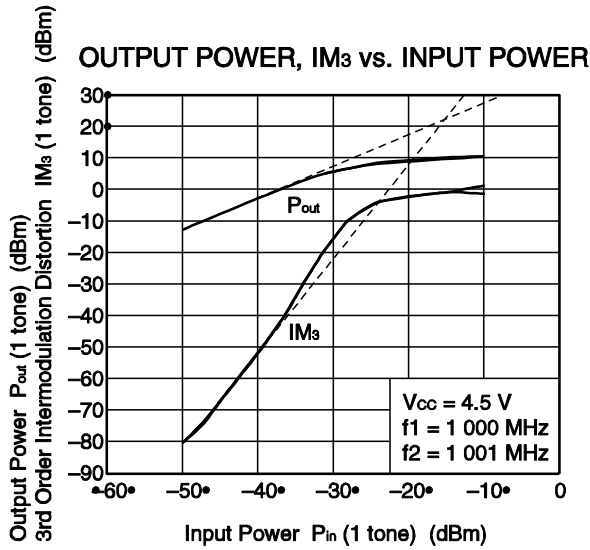
OUTPUT POWER vs. INPUT POWER



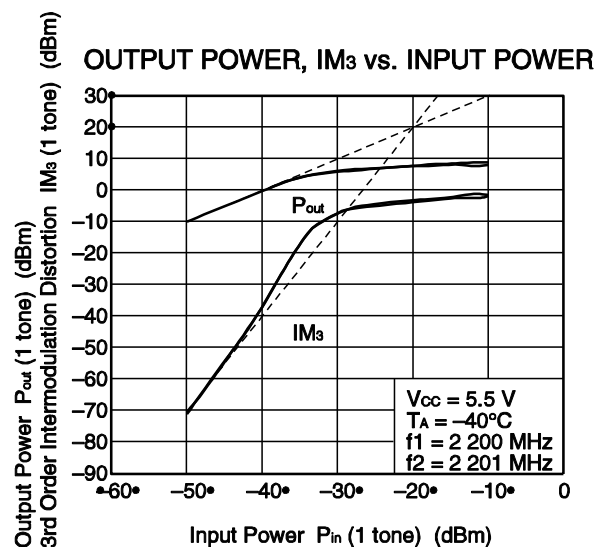
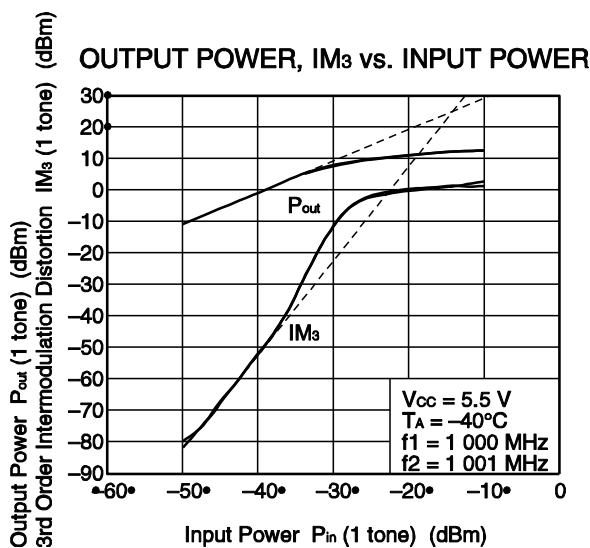
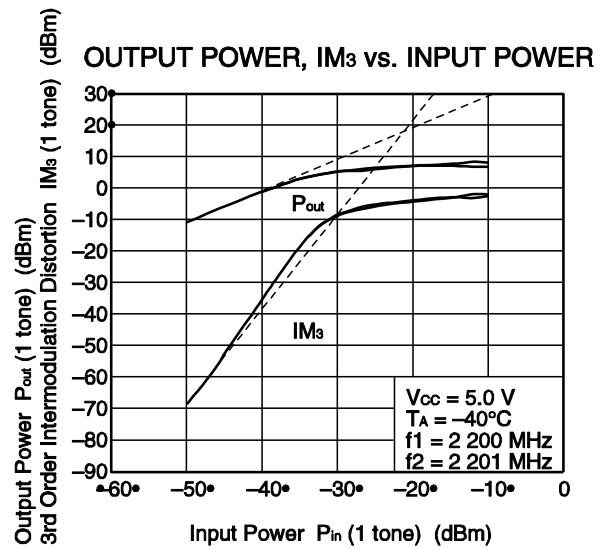
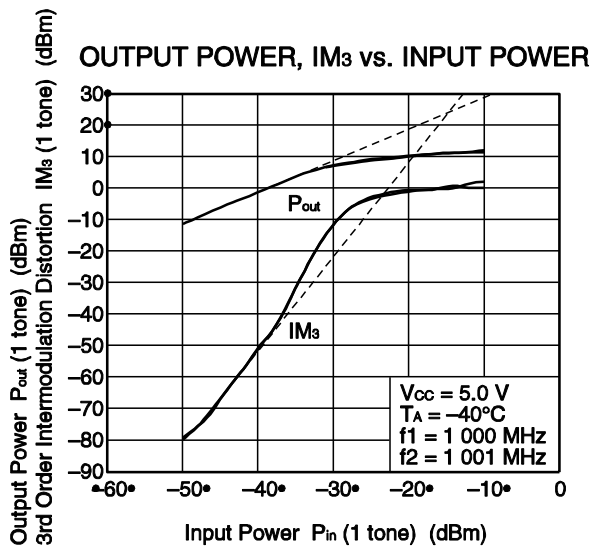
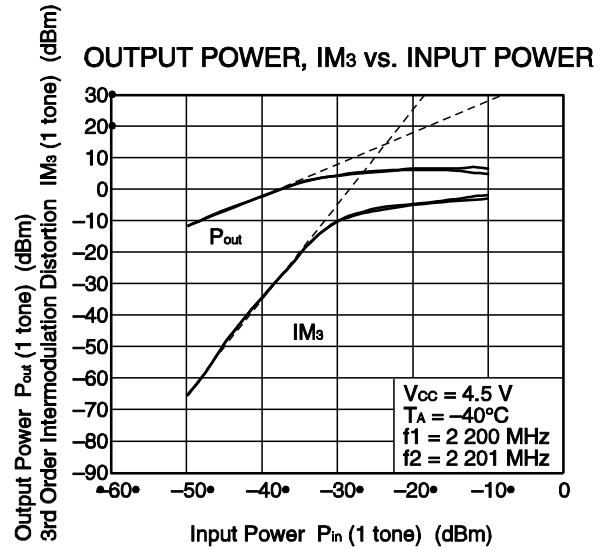
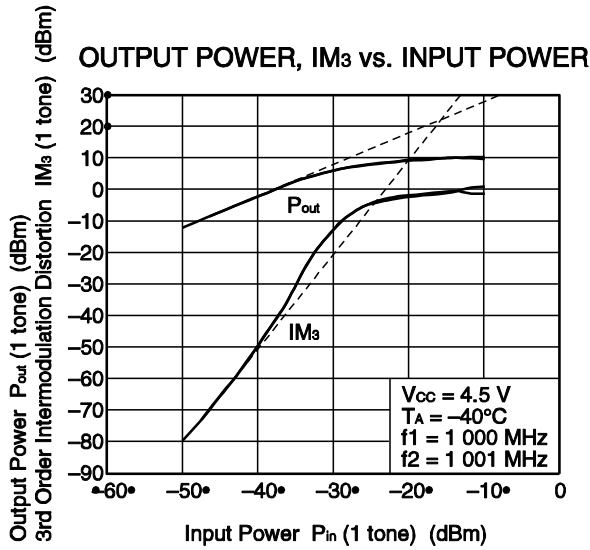
Remark The graphs indicate nominal characteristics.



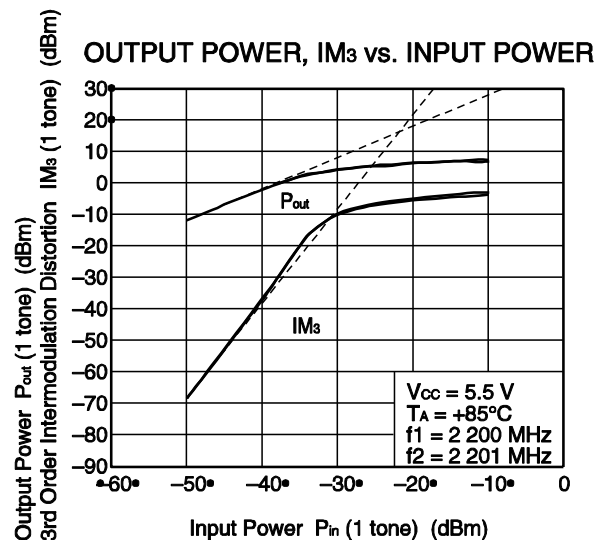
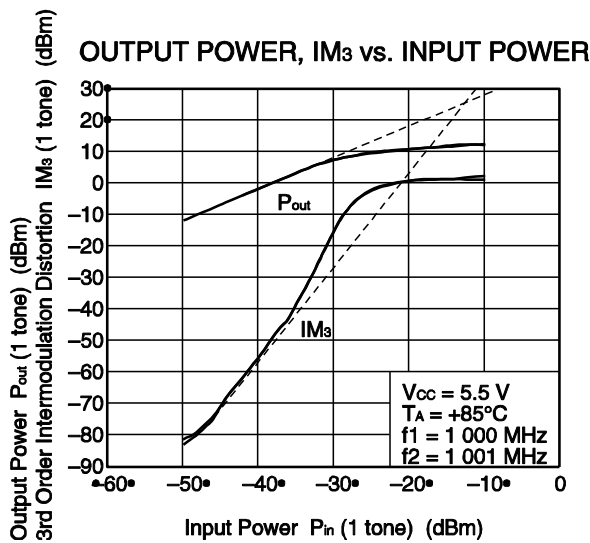
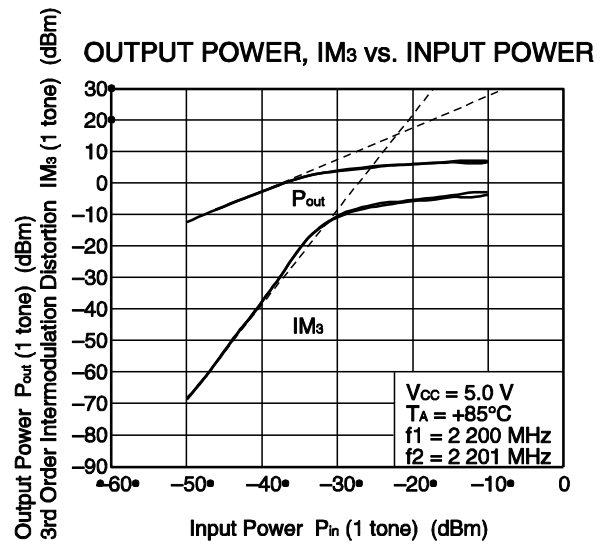
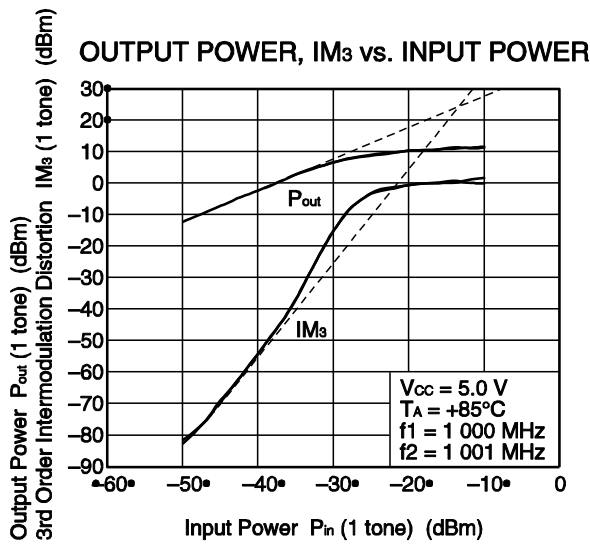
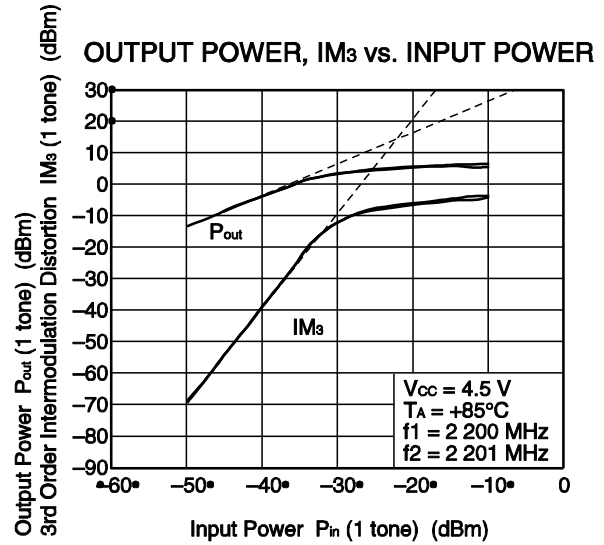
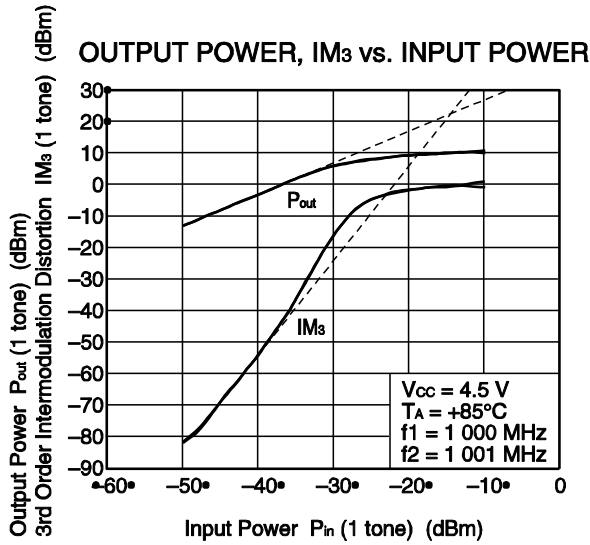
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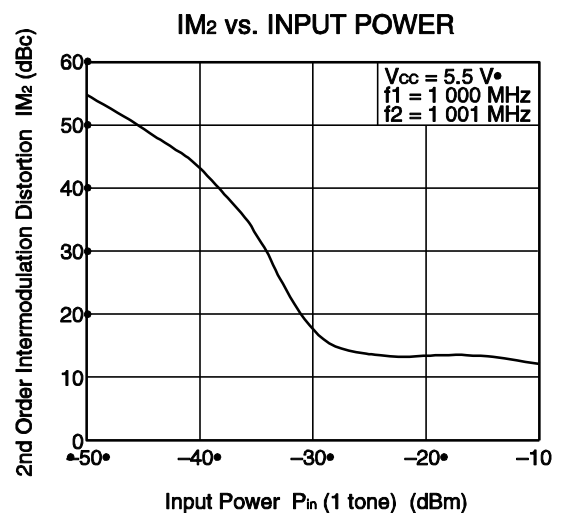
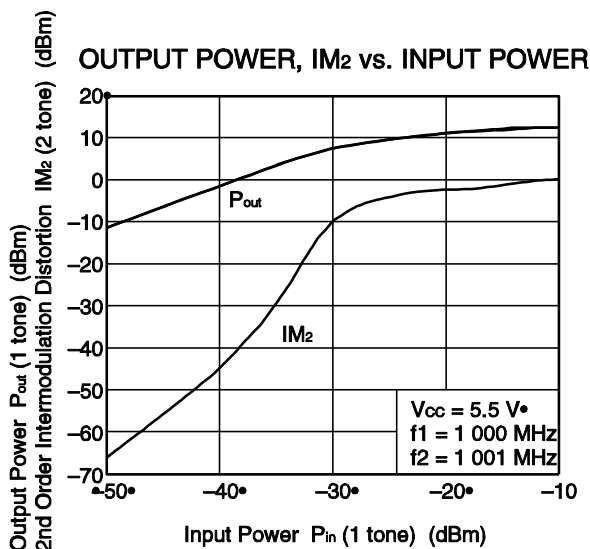
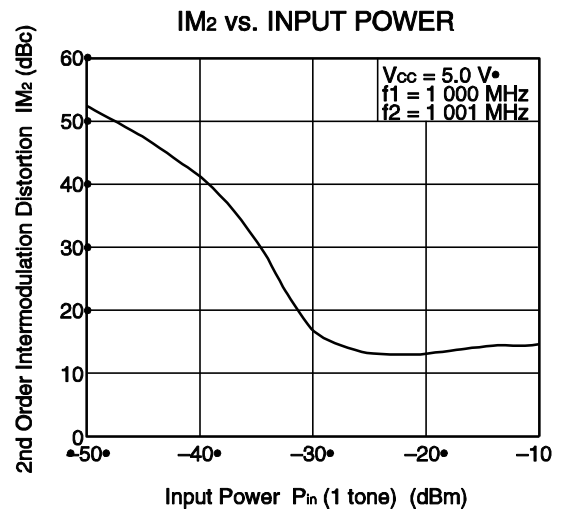
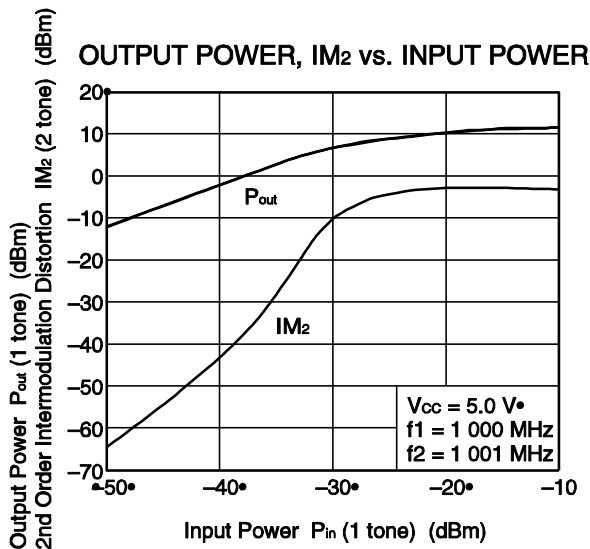
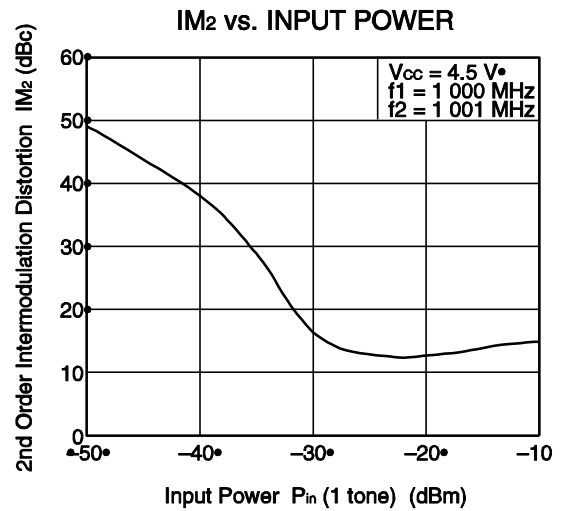
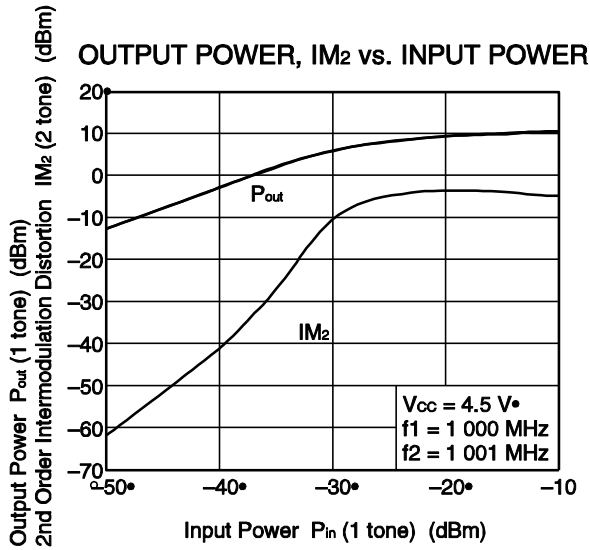
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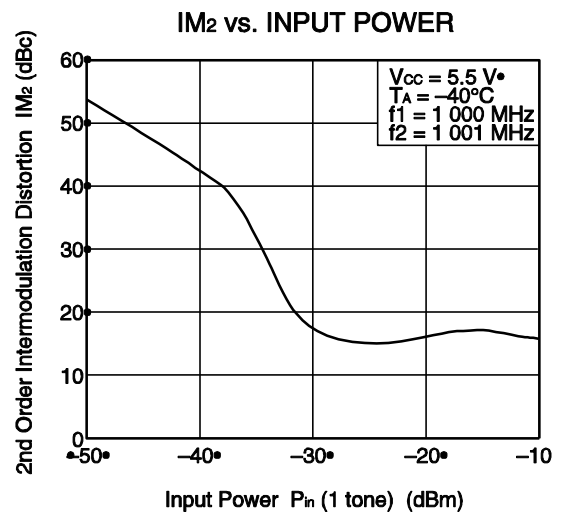
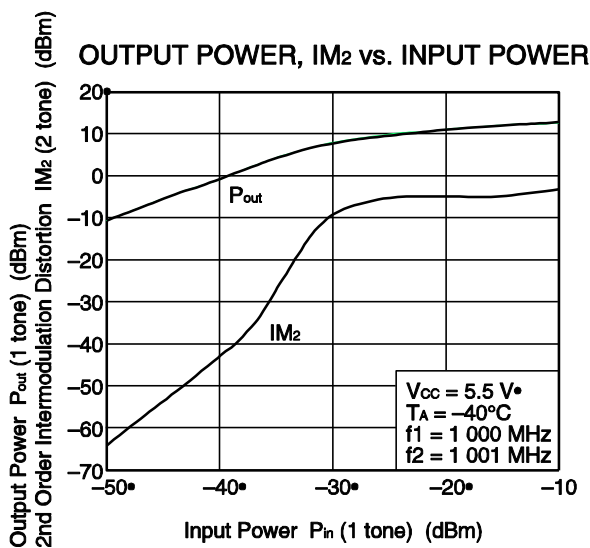
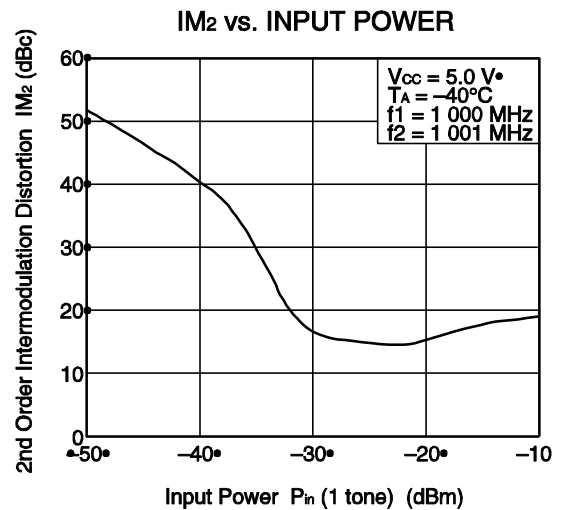
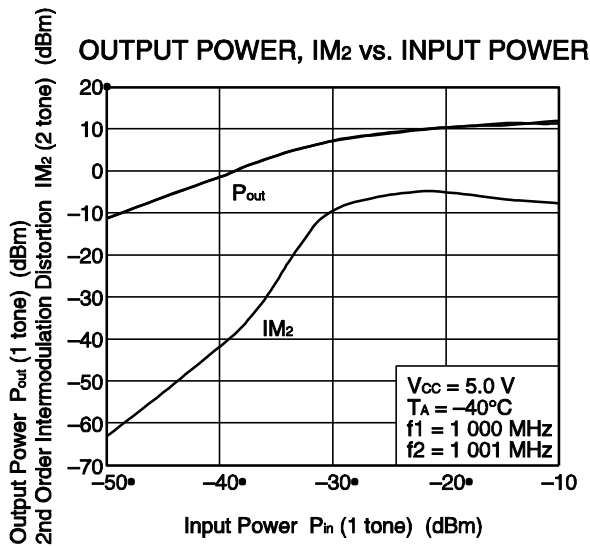
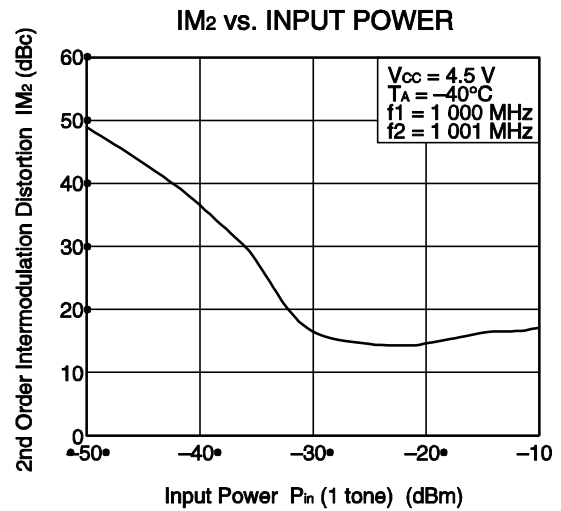
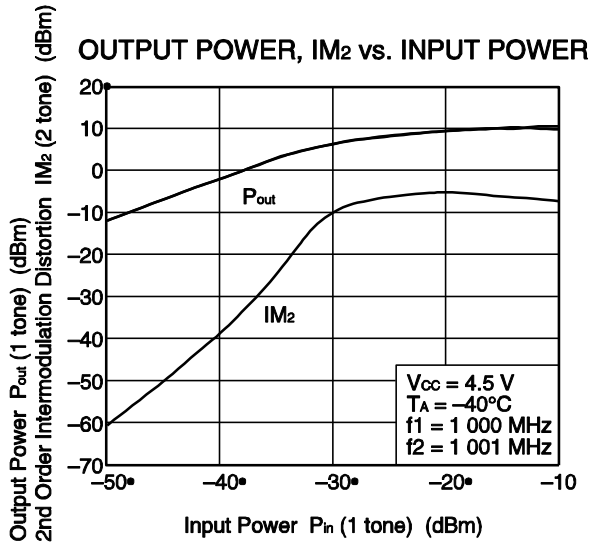
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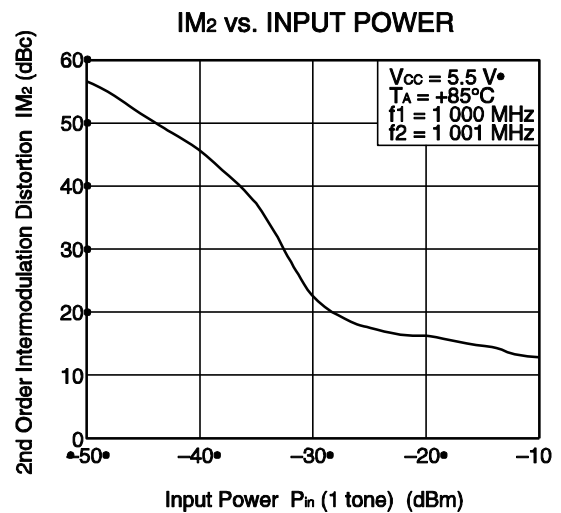
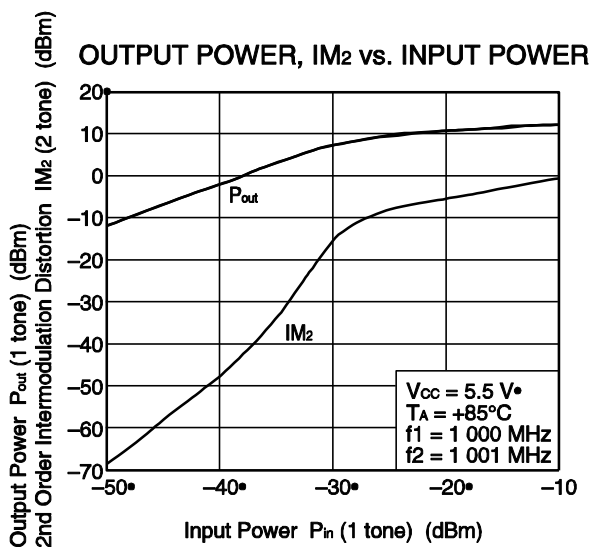
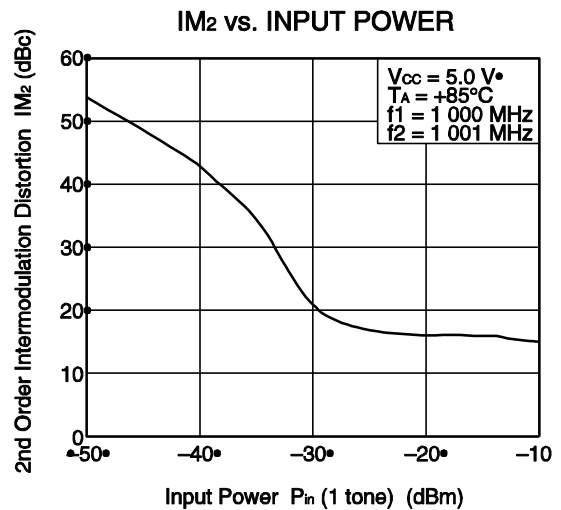
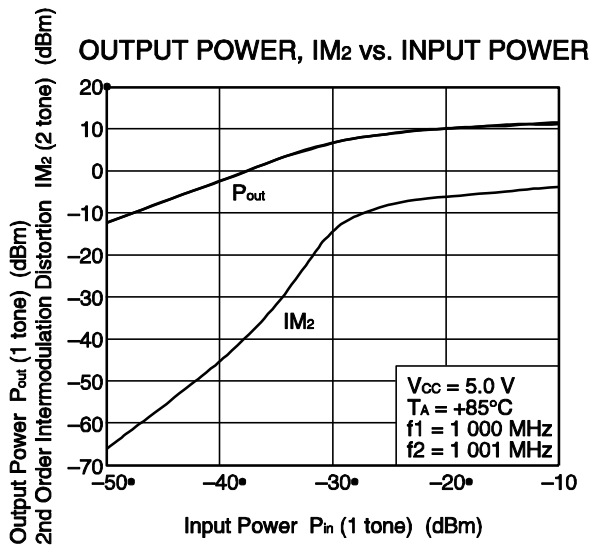
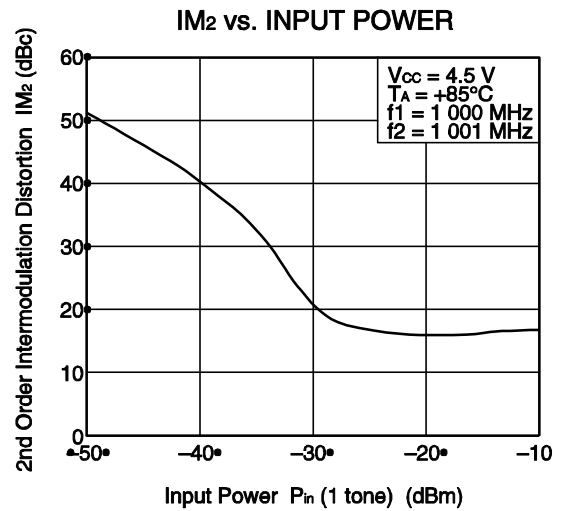
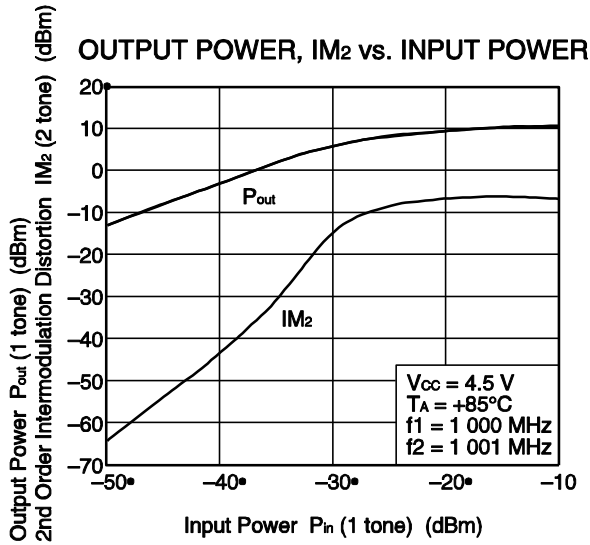
Remark The graphs indicate nominal characteristics.



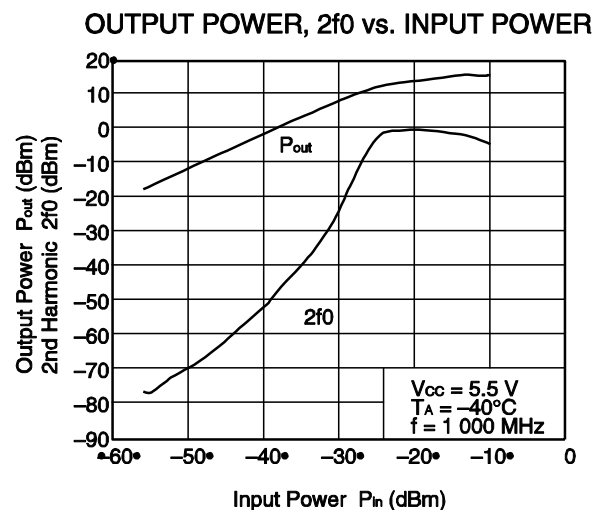
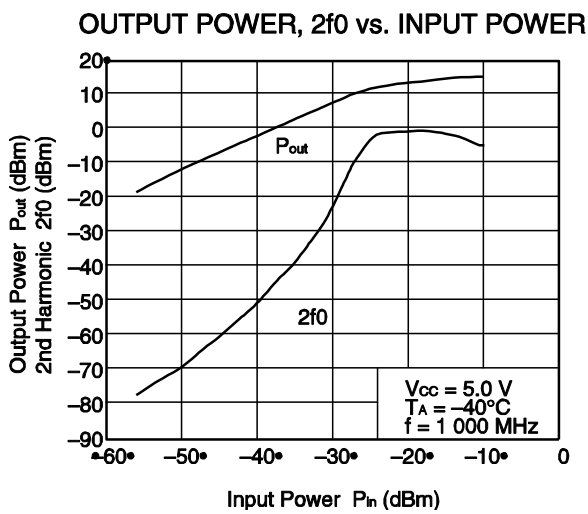
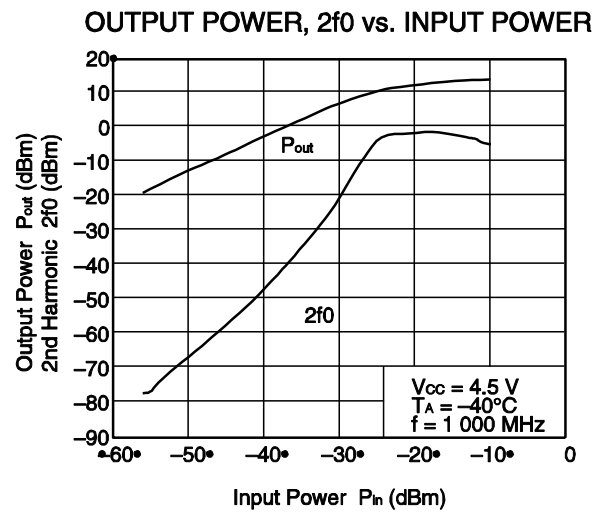
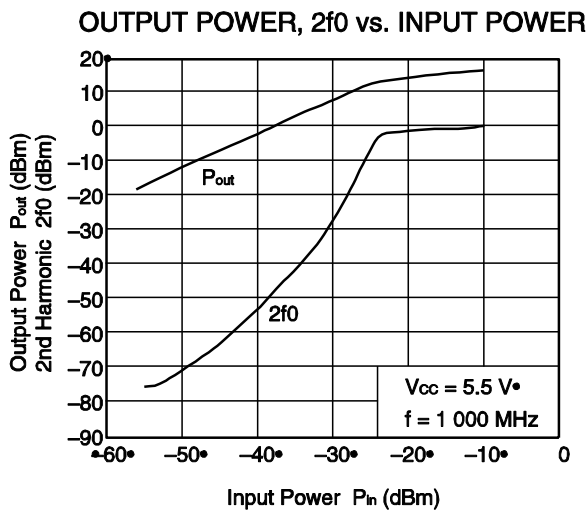
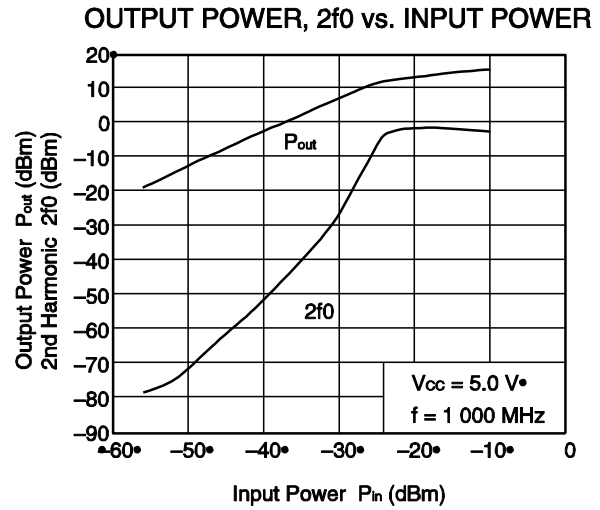
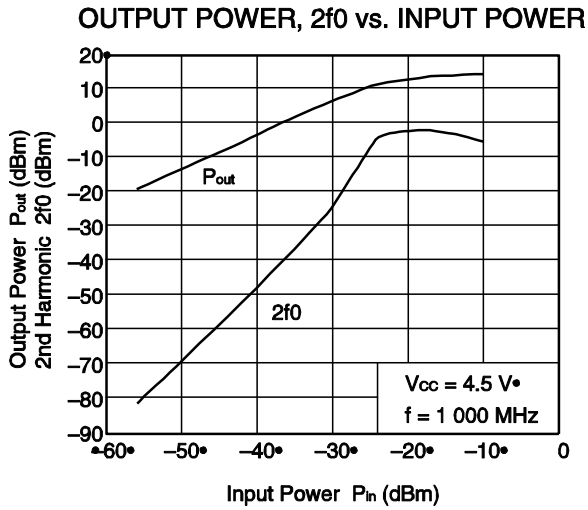
Remark The graphs indicate nominal characteristics.



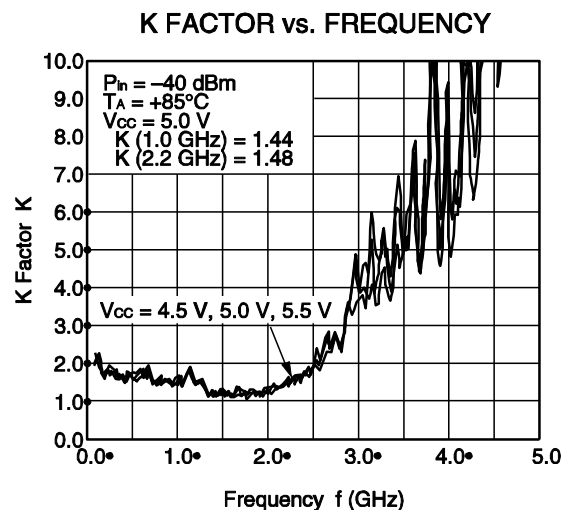
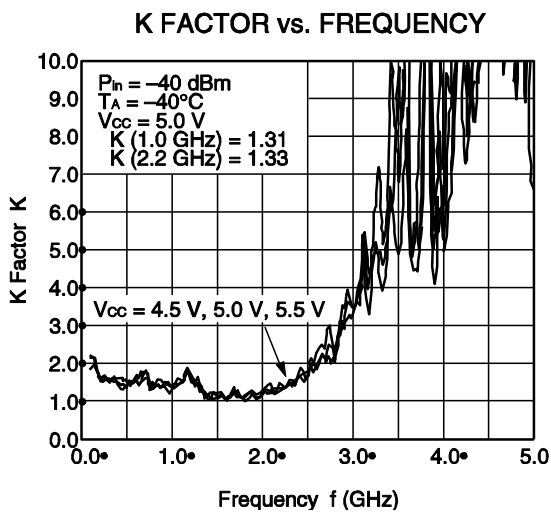
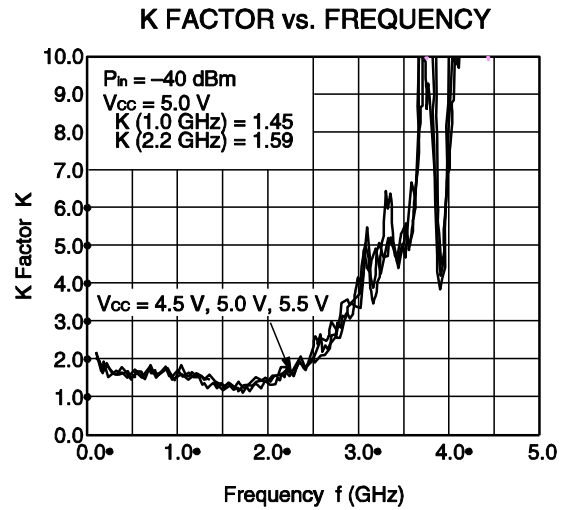
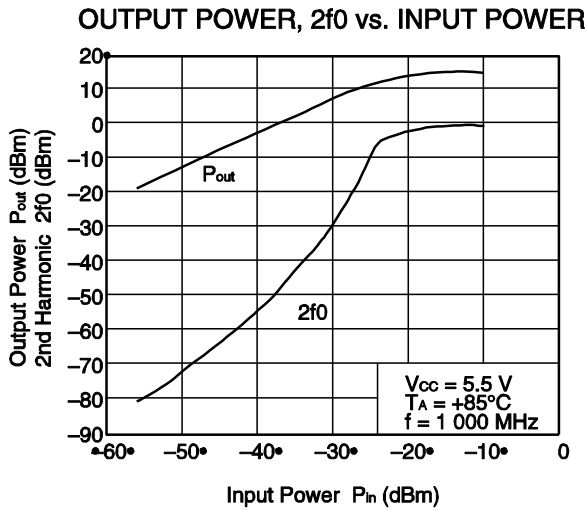
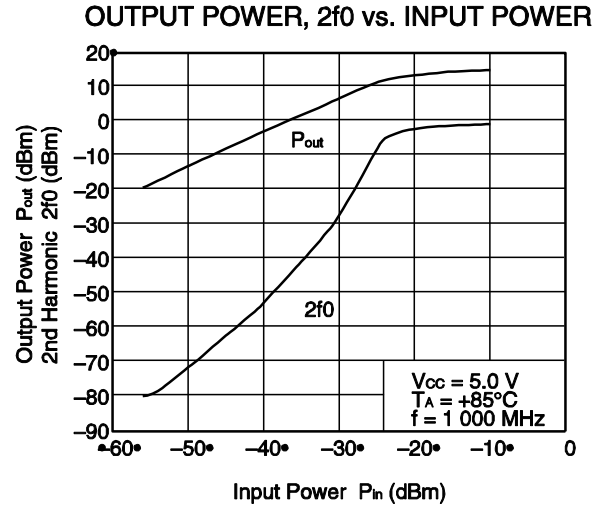
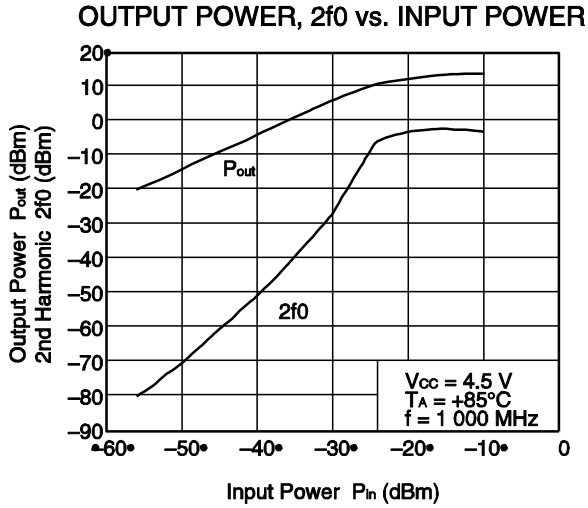
Remark The graphs indicate nominal characteristics.



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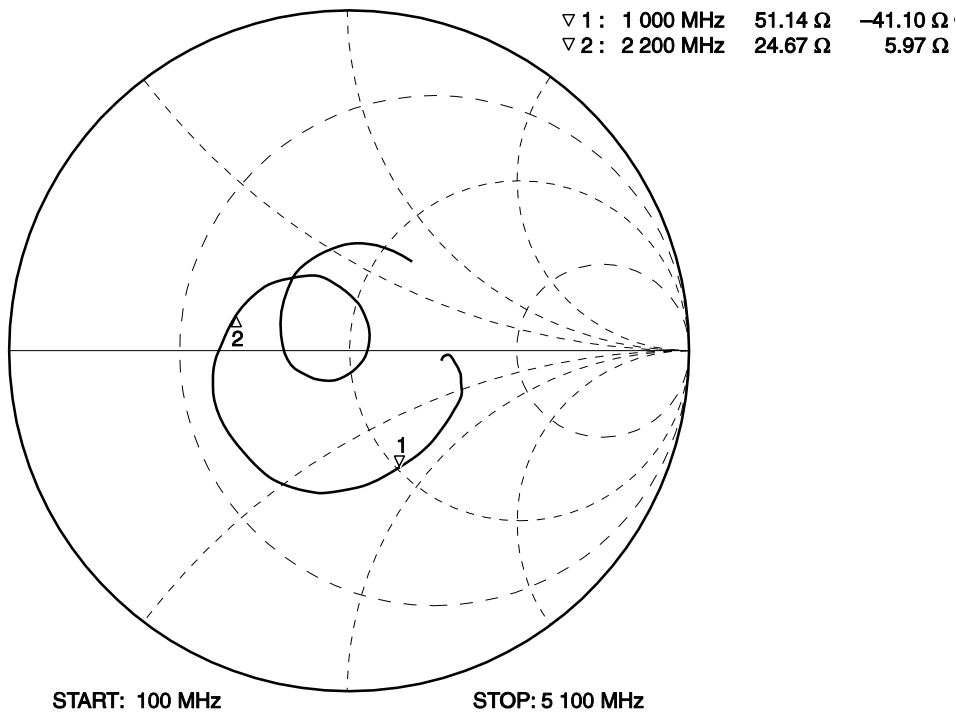
Remark The graphs indicate nominal characteristics.



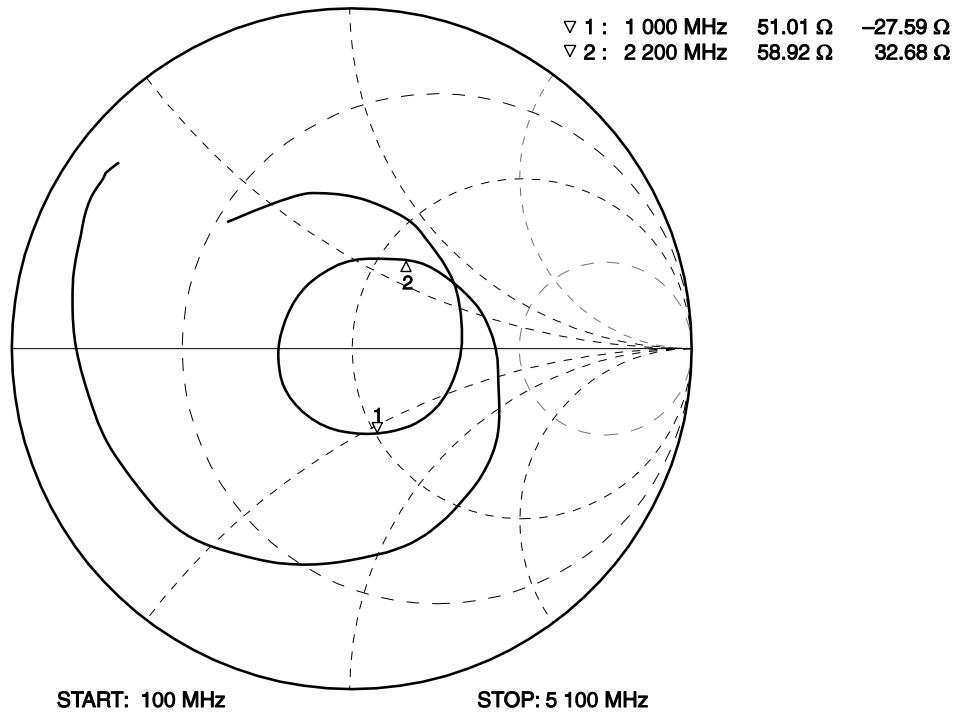
Remark The graphs indicate nominal characteristics.

S-PARAMETERS ($T_A = +25^\circ\text{C}$, $V_{CC} = V_{out} = 5.0\text{ V}$, $P_{in} = -40\text{ dBm}$)

S₁₁-FREQUENCY



S₂₂-FREQUENCY



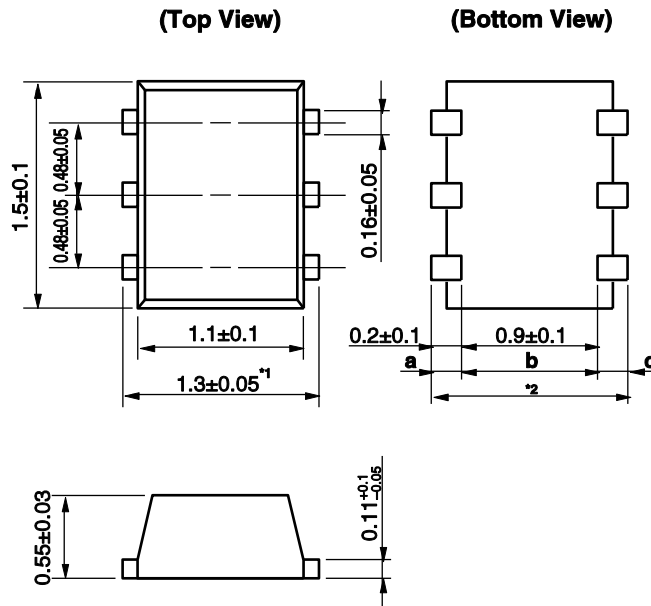
- Remarks**
1. Measured on the test circuit of evaluation board.
 2. The graphs indicate nominal characteristics.

S-PARAMETERS

- S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.
- [Click here to download S-parameters.](#)
- [\[RF and Microwave\] ® \[Device Parameters\]](#)
- URL <http://www.necel.com/microwave/en/>

PACKAGE DIMENSIONS

6-PIN LEAD-LESS MINIMOLD (1511 PKG) (UNIT: mm)



Remark Dimension¹ is bigger than dimension² (dimension² = a + b + c).

NOTES ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation).
There are the surface GND pattern area that must be separated to make stability.
- (3) The bypass capacitor should be attached to the Vcc line.
- (4) The inductor (L) must be attached between Vcc and output pins. The inductance value should be determined in accordance with desired frequency.
- (5) The DC cut capacitor must be attached to input and output pin.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) : 260°C or below Time at peak temperature : 10 seconds or less Time at temperature of 220°C or higher : 60 seconds or less Preheating time at 120 to 180°C : 120±30 seconds Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	IR260
Wave Soldering	Peak temperature (molten solder temperature) : 260°C or below Time at peak temperature : 10 seconds or less Preheating temperature (package surface temperature) : 120°C or below Maximum number of flow processes : 1 time Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	WS260
Partial Heating	Peak temperature (terminal temperature) : 350°C or below Soldering time (per side of device) : 3 seconds or less Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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